

## DESCRIPTION

ESD5451N is a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for data, control or power lines. With typical capacitance of 8pF only, ESD5451N is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 ( $\pm 15\text{kV}$  air,  $\pm 8\text{kV}$  contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

## FEATURES

- ✧ Transient protection for high-speed data lines  
IEC 61000-4-2 (ESD)  $\pm 15\text{kV}$  (Air)  
 $\pm 8\text{kV}$  (Contact)
- IEC 61000-4-4 (EFT) 40A (5/50 ns)  
Cable Discharge Event (CDE)
- ✧ Package optimized for high-speed lines
- ✧ Ultra-small package (1.0mm $\times$ 0.6mm $\times$ 0.4mm)
- ✧ Protects one data, control or power line
- ✧ Low capacitance
- ✧ Low leakage current
- ✧ Low clamping voltage
- ✧ Each I/O pin can withstand over 1000 ESD strikes for  $\pm 8\text{kV}$  contact discharge

## MACHANICAL DATA

- ✧ DFN1006 package
- ✧ Flammability Rating: UL 94V-0
- ✧ Packaging: Tape and Reel
- ✧ High temperature soldering guaranteed:  $260^\circ\text{C}/10\text{s}$
- ✧ Reel size: 7 inch

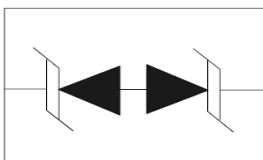
## ORDERING INFORMATION

- ✧ Package: DFN1006
- ✧ Material: RoHS compliant, Halogen free
- ✧ Packing: Tape & Reel
- ✧ Quantity per reel: 10,000pcs

## APPLICATIONS

- ✧ Portable Electronics
- ✧ Desktops, Servers and Notebooks
- ✧ Cellular Phones
- ✧ MP3 Ports
- ✧ Digital Ports
- ✧ Subscriber Identity Module (SIM) card

## CIRCUIT DIAGRAM



## PIN CONFIGURATION



**ABSOLUTE MAXIMUM RATING**

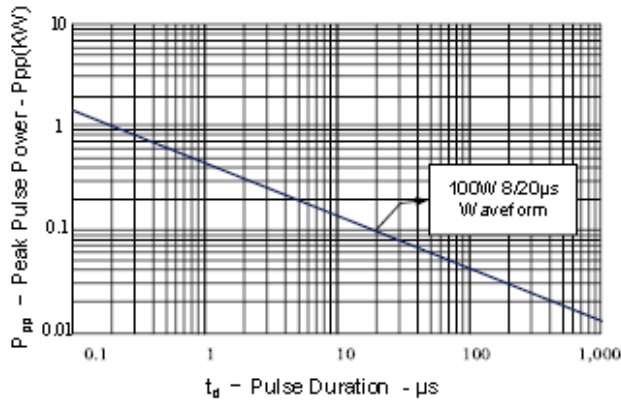
Symbol	Parameter	Value	Units
$P_{PP}$	Peak Pulse Power (8/20 $\mu$ s)	100	W
$T_j$	Operating Temperature	-55/+125	$^{\circ}$ C
$T_{STG}$	Storage Temperature	-55/+150	$^{\circ}$ C

**ELECTRICAL CHARACTERISTICS ( $T_{amb}=25^{\circ}$ C)**

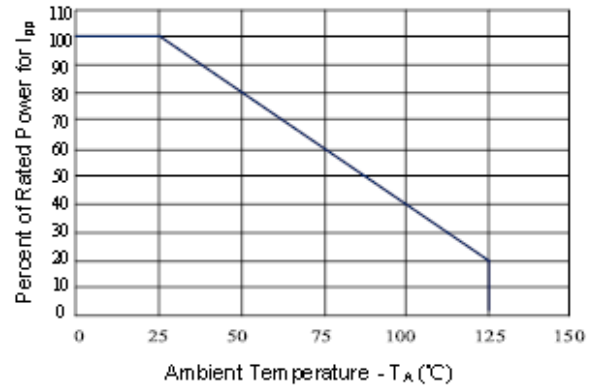
Symbol	Parameter	Test Condition	Min	Typ	Max	Units
$V_{RWM}$	Reverse Stand-Off Voltage				5.0	V
$V_{BR}$	Reverse Breakdown voltage	$I_T=1mA$	6.0			V
$I_R$	Reverse leakage current.	$V_{RWM}=5V$			1	$\mu$ A
$I_{PP}$	Peak Pulse Current	$t_p=8/20\mu s$			5	A
$V_C$	Clamping Voltage	$I_{PP}=1A, t_p=8/20\mu s$ $I_{PP}=5A, t_p=8/20\mu s$		13	9.5 15	V
$C_J$	Junction Capacitance	$V_R=0V, f=1MHz$		8	15	pF

**ELECTRICAL CHARACTERISTICS CURVE**

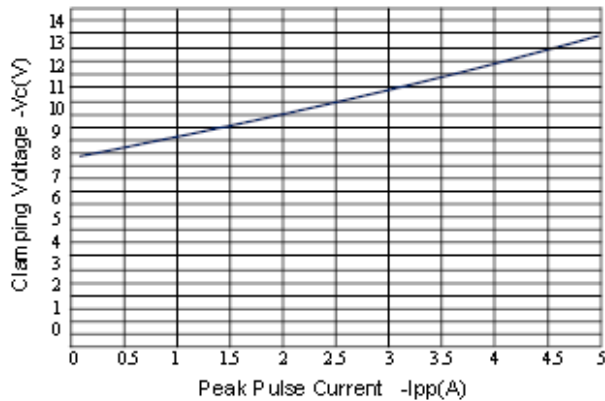
**Figure 1: Peak Pulse Power Vs Pulse Time**



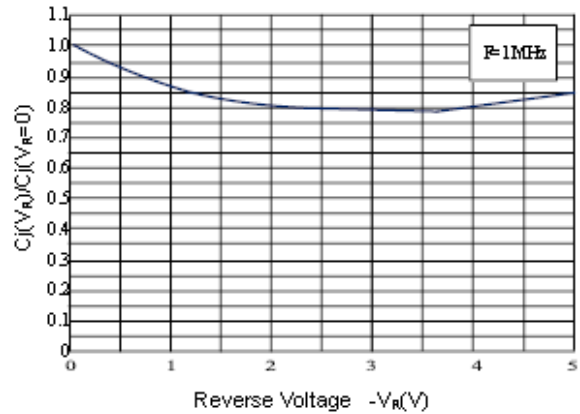
**Figure 2: Power Derating Curve**



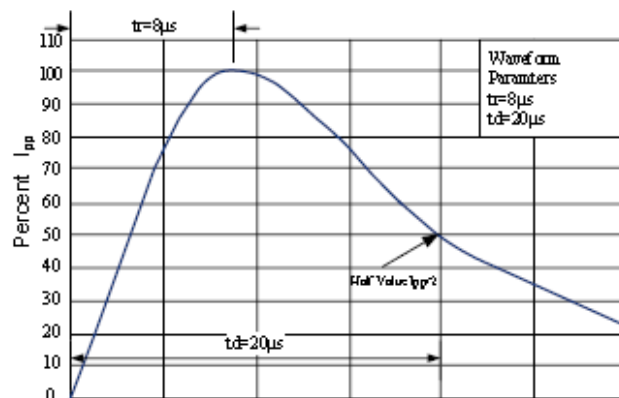
**Figure 3: Clamping Voltage vs. Peak Pulse Current**



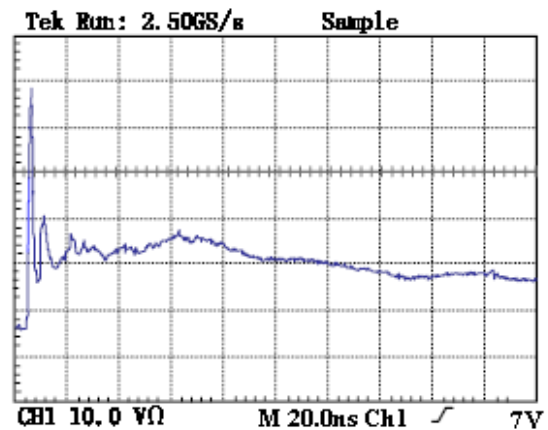
**Figure 4: Normalized Junction Capacitance vs. Reverse Voltage**



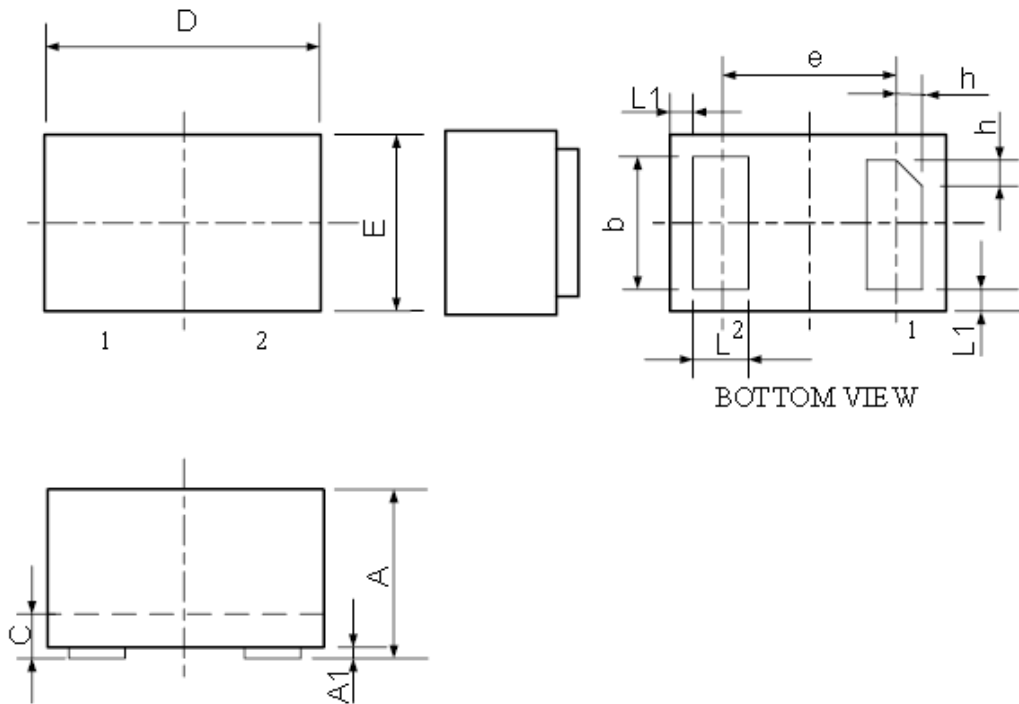
**Figure 5: Pulse Waveform**



**Figure 6: ESD Clamping (8kV Contact per IEC 61000-4-2)**



**DFN1006 PACKAGE OUTLINE DIMENSIONS**



Symbol	Dimensions In Millimeters	
	Minimum	Maximum
A	0.450	0.550
A1	0.000	0.050
b	0.45	0.55
C	0.12	0.18
D	0.950	1.050
e	0.65BSC	
E	0.550	0.650
L	0.200	0.300
L1	0.05REF	
h	0.07	0.17

单击下面可查看定价，库存，交付和生命周期等信息

[>>KUU\(永裕泰\)](#)